Small Signal Switching Diodes, High Voltage



FEATURES

- Silicon epitaxial planar diodes
- For general purpose
- AEC-Q101 qualified available
  (part number on request)
- Base P/N-G3 - green, commercial grade
- Material categorization:
  for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

e3

RoHS COMPLIANT

HALOGEN FREE GREEN (5-2008)

DESIGN SUPPORT TOOLS

click logo to get started

3D Models Available

MECHANICAL DATA

Case: SOD-123
Weight: approx. 9.4 mg
Packaging codes / options:
18/10K per 13" reel (8 mm tape), 10K/box
08/3K per 7" reel (8 mm tape), 15K/box

PARTS TABLE

PART	TYPE DIFFERENTIATION	ORDERING CODE	TYPE MARKING	CIRCUIT CONFIGURATION	REMARKS
BAV19W-G	V_R = 100 V	BAV19W-G3-08 or BAV19W-G3-18	AS	Single	Tape and reel
BAV20W-G	V_R = 150 V	BAV20W-G3-08 or BAV20W-G3-18	AT	Single	Tape and reel
BAV21W-G	V_R = 200 V	BAV21W-G3-08 or BAV21W-G3-18	AU	Single	Tape and reel

ABSOLUTE MAXIMUM RATINGS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	PART	SYMBOL	VALUE	UNIT
Continuous reverse voltage		BAV19W-G	V_R	100	V
		BAV20W-G	V_R	150	V
		BAV21W-G	V_R	200	V
Repetitive peak reverse voltage		BAV19W-G	V_{RRM}	120	V
		BAV20W-G	V_{RRM}	200	V
		BAV21W-G	V_{RRM}	250	V
DC forward current (1)			I_F	250	mA
Rectified current (average) half wave rectification with resist. load (1)			$I_{F(AV)}$	200	mA
Repetitive peak forward current (1)	f ≥ 50 Hz		I_{FRM}	625	mA
Surge forward current	t < 1 s		I_{FSM}	1	A
Power dissipation (1)			P_{tot}	410	mW

THERMAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Thermal resistance junction to ambient air (1)		R_{thJA}	375	K/W
Junction temperature (1)		T_j	150	°C
Storage temperature range (1)		T_{stg}	-65 to +150	°C
Operating temperature range		T_{op}	-55 to +150	°C

Note
(1) Valid provided that leads are kept at ambient temperature

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ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN.**	**TYP.**	**MAX.**	**UNIT**
Forward voltage	I_F = 100 mA		V_F			1	V
	I_F = 200 mA		V_F			1250	mV
Leakage current	V_R = 100 V	BAV19W-G	I_R			100	nA
	V_R = 100 V, T_j = 100 °C	BAV19W-G	I_R			15	µA
	V_R = 150 V	BAV20W-G	I_R			100	nA
	V_R = 150 V, T_j = 100 °C	BAV20W-G	I_R			15	µA
	V_R = 200 V	BAV21W-G	I_R			100	nA
	V_R = 200 V, T_j = 100 °C	BAV21W-G	I_R			15	µA
Dynamic forward resistance	I_F = 10 mA		r_f		5		Ω
Diode capacitance	V_R = 0, f = 1 MHz		C_D		1.5		pF
Reverse recovery time	I_F = 30 mA, I_R = 30 mA, i_R = 3 mA, R_L = 100 Ω		t_{rr}			50	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

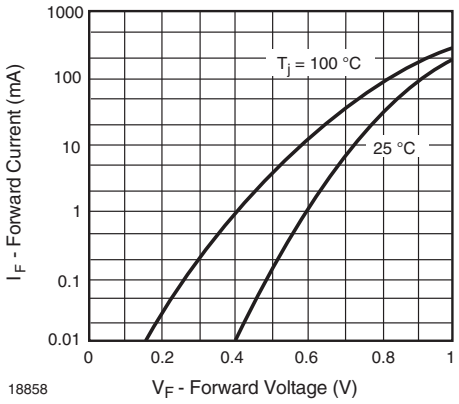


Fig. 1 - Forward Current vs. Forward Voltage

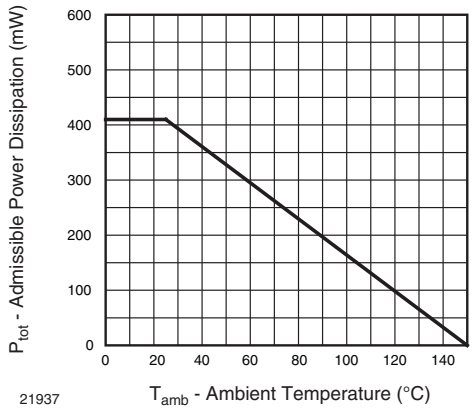


Fig. 3 - Admissible Power Dissipation vs. Ambient Temperature

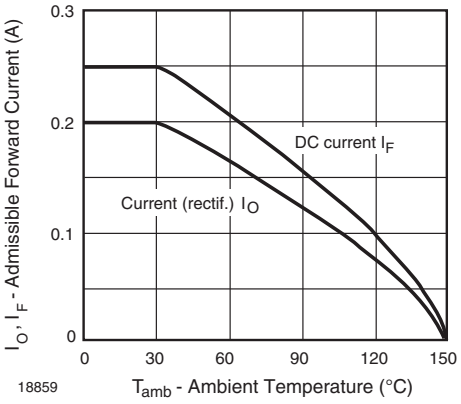


Fig. 2 - Admissible Forward Current vs. Ambient Temperature

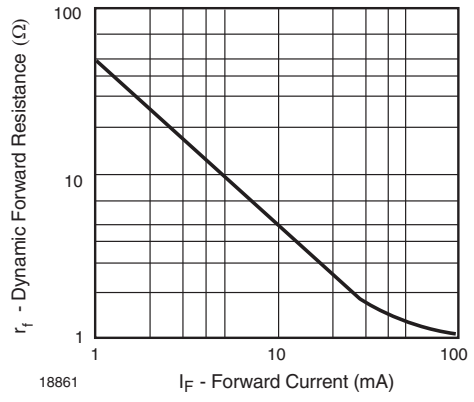


Fig. 4 - Dynamic Forward Resistance vs. Forward Current

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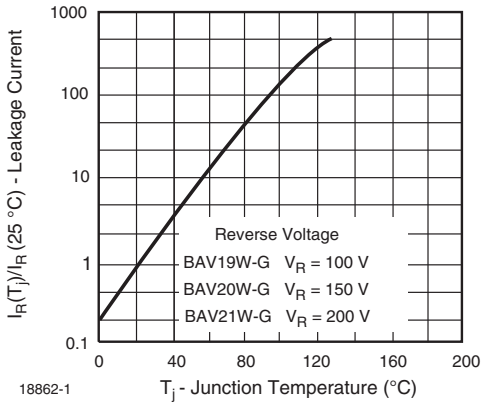


Fig. 5 - Leakage Current vs. Junction Temperature

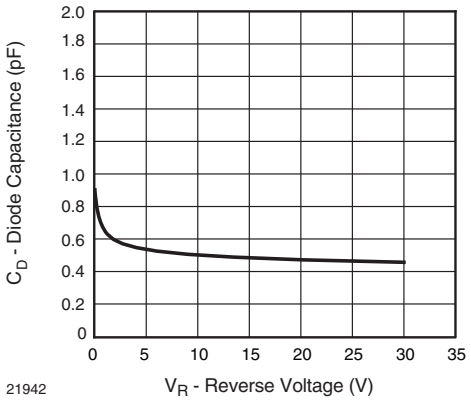


Fig. 6 - Diodes Capacitance vs. Reverse Voltage

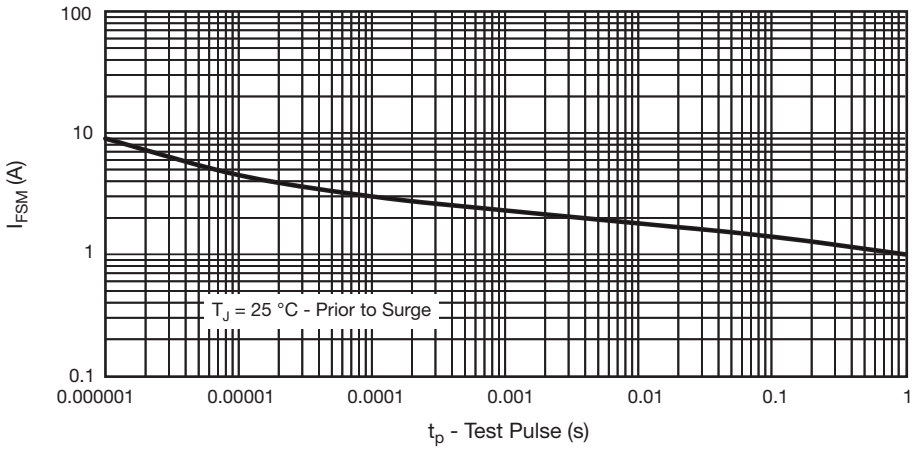
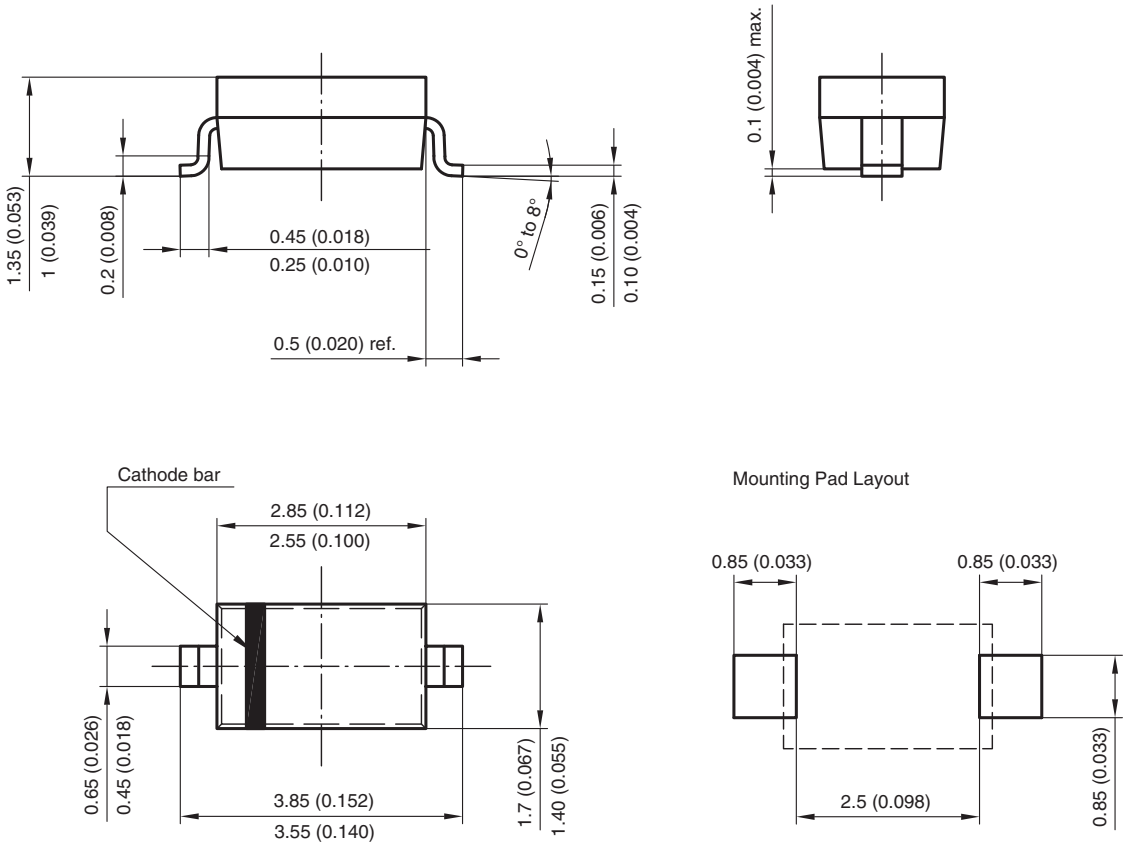


Fig. 7 - Non-Repetitive Peak Forward Current vs. Pulse Duration
Maximum Admissible Values of Square Pulses

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PACKAGE DIMENSIONS in millimeters (inches): **SOD-123**



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